

WECH CENTER 2800

SUPPLEMENTAL DECLARATION FOR REISSUE PATENT APPLICATION (37 CFR 1.175)

Atterney Docket No.	211836US2SRD RE	
First Named Inventor	Yasus OHBA, et al.	
Bertal Number	09/915,710	
Filing Date	July 27, 2001	
Group Aft Unit	2815	
Exeminer	Jerome Jackson, Jr.	

I/We hereby declare that:	
Every error in the patent which was corrected in the pri and/or declaration(s) submitted in this application, arose	seant release application, and which is not covered by the prior ogen(e without any deceptive intention on the part of the applicant.
Information and belief are believed to be true; and furthe	of my/our own knowledge are true and that all statements made or or that these statements were made with the knowledge that willful fals or imprisonment, or both, under 18 U.S.C. 1001, and that such willful estion or any patent issuing thereon.
Full Name of sole or first inventor (given name, family name) Yasuo Ohba	
Signature Yasur Ohba	Date May 13, 2004
Residence Yokohama, Japan	Classiship Japan
Post Office Address 9-8-1-109 Hino Kounan-ku, Yokohama	-shi, Kanasawa-ken, Japan 234-0051
Full Name of second joint inventor (given name, family manus) Also Hatano	
Bignisture also Itatanio	Date May 20, 2004
Residence Tokyo, Japan	Crizeratăp Japan
Post Office Address 2-20-5-804 Nishiwaseda, Shinjuku-ku,	Tokyo-to, Jepan 162-0051
Full Name of third joint inventor (given name, family name)	
Signature	Date
Residence	Citizenship
Post Office Address	
Full Name of fourth joint (nventor (given name, family name)	
Signature:	Date
Residence	Chizonehip
Post Office Address	
☐ Additional joint inventors are named on separate	ly numbered sheets attached heretg.



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MAY 28 2004

DOCKET NO: 211836US2SRD RE

TECH CENTER 2800

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

YASUO OHBA, ET AL.

: EXAMINER: JEROME JACKSON IR.

}

SERIAL NO: 09/915,710

FILED: JULY 27, 2001

: GROUP ART UNIT: 2815

FOR: SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING THE SAME

37 CFR §1.175 REISSUE DECLARATION (CORRECTED)

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

I. 37 CFR 1.172 Declaration by the Assignee

The written consent to this reissue application by the assignee owning the entire interest in the patent has been previously filed.

II. 37 CFR 1.175

A. 37 CFR 1.175(a)

1. 37 CFR 1.63(a)(1)

This declaration is executed in accordance with 37 CFR 1.68. Specifically, the undersigned have been warned that willful false statements and the like are punishable by fine or imprisonment, or both (18 U.S.C. 1001), and willful false statements may jeopardize the validity of this application or any patent issuing thereon. All of the undersigned's statements based upon personal knowledge are true, and all of the undersigned's statements made on information and belief are believed to be true.

2. 37 CFR 1.63(a)(2)

There are two inventors. The full name of the first inventor is Yasuo Ohba. The full name of the second inventor is Ako Hatano. Yasuo Ohba and Ako Hatano are joint inventors of the inventions claimed.

3. 37 CFR 1.63(a)(3)

Yasuo Ohba and Ako Hatano are both citizens of Japan.

4. 37 CFR 1.63(a)(4)

The inventors believe that they are the original and first inventors of the subject matter which is claimed and for which a patent is sought.

5. 37 CFR 1.63(b)(1)

This declaration is directed to the application for the reissue of U.S. 5,929,466, filed July 27, 2001.

6. 37 CFR 1.63(b)(2)

The inventors have each reviewed and understand the contents of the specification, including the claims, as amended in the reissue application filed July 27, 2001.

7. 37 CFR 1.63(b)(3)

The inventors each acknowledge their duty to disclose to the U.S. Patent Office all information known to him to be material to patentability as defined in 37 CFR 1.56.

8. 37 CFR 1.63(c)(1)

Yasuo Ohba's residence and Post Office address is 3-8-1-109 Hinn Kounan-kn, Yokohama-shi, Kanagawa-ken, Japan 234-0051.

Ako Hatano's residence and Post Office address is 2-20-5-804 Nishiwaseda, Shinjuku-ku, Tokyo-to, Japan 162-0051.

9. 37 CFR 1.63(c)(2)

The foreign applications are Japanese Patent No. 6-038157 filed March 9, 1994 and Japanese Patent No. 7-000704 filed January 6, 1995. Priority is claimed from these applications.

10. 37 CFR 1.63(d)

This section is not applicable.

11, 37 CFR 1.63(e)

This section is not applicable.

B. 37 CFR 1.175(a)(1)

The applicants believe the original patent to be wholly or partly inoperative or invalid by reason of the patentee claiming more or less than the patentee had the right to claim in the patent. The applicants seek to broaden the scope of the original claims. One error was the failure in U.S. 5,929,466 to claim the subject matter of reissuc claim 11,

namely, a semiconductor device having in addition to the subject matter of claim 1 of 5,929,466, a substrate, said buffer semiconductor 1 yer being formed on said substrate, and said pinholes comprising exposed portions of said substrate through said buffer.

C. 37 CFR 1.175(a)(2)

All errors being corrected in the reissue application arose without any deceptive intention on the part of the applicants.

III. 37 CFR 1.175(b)

Every error addressed by the claims filed in the reissue application gross without any deceptive intention on the part of the applicant.

IV. 37 CFR 1.175(c)

This section provides no additional requirements.

V. 37 CFR 1.175(d)

This section is not applicable.

VI. Jurat

The inventors each declare under penalty of perjury of the laws of the United States that the foregoing is true and correct.

your ohba	Yasuo Ohba
May 13, 2004	Date Signed
aho Hatano	Ako Hatano
May 20, 20.4	Date Signed